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Nonequilibrium resonant spectroscopy of molecular vibrons

Dmitry A. Ryndyk and Gianaurelio Cuniberti
Institut für Theoretische Physik, Universität Regensburg, D-93040 Germany

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Quantum transport through single molecules is essentially affected by molecular vibrations. We investigate the behavior of the prototype single-level model with intermediate electron-vibron coupling and arbitrary coupling to the leads. We have developed a theory which allows to explore this regime via the nonequilibrium Green function formalism. We show that the nonequilibrium resonant spectroscopy is able to determine the energies of molecular orbitals and the spectrum of molecular vibrations. Our results are relevant to scanning tunneling spectroscopy experiments, and demonstrate the importance of the systematic and self-consistent investigation of the effects of the vibronic dynamics onto the transport through single molecules.

Molecular electronics [1, 2, 3] is the most promising development of nano-electronics, raising new theoretical challenges and calling for new methods. The understanding of quantum electron transport at the molecular scale is a key step to future devices. Recently, the interaction of electrons with molecular vibrations attracted an enormous attention unveiled by electron transport experiments through single molecules [4, 5, 6, 7, 8, 9]. In scanning tunneling spectroscopy (STS) experiments clear signatures of the electron-vibron interaction have been observed [10, 11, 12, 13]. In these experiments both the electron-vibron coupling and the electron hybridization are well beyond the perturbation limit, so that a theory beyond the linear response or master equation approaches is necessary. In this Letter, we present such a theory and discuss the vibronic features in the current-voltage curves of molecular junctions as a spectroscopic tool.

Resonant electron transport through a molecular orbital with electron-vibron interaction at finite voltages is essentially different from the well known inelastic electron tunneling spectroscopy (IETS). Indeed, in the IETS situation one has typically the multi-channel tunneling between two bulk metals with continuous density of states, and an *increase* of the conductance is observed when the bias voltage exceeds the threshold determined by the frequency of vibrational mode. As we shall see below, in resonant tunneling through molecular levels coupled to vibrons, the situation is very different: in addition to the usual IETS signal, the inelastic signal can be observed as an extra *peak* in the differential conductance, or just as a *decrease* of the conductance. The resulting signal is determined by the energy of the electronic state, the vibronic frequency, the electron-vibron coupling, and the molecule-to-lead coupling. The position of the molecular energy levels could be changed by the external gate voltage, but in the STS experiments the application of the gate voltage is not possible, instead the tip-to-molecule distance can be changed, also changing the molecule-to-tip coupling [11]. Thus it is very important to investigate quantum transport at arbitrary coupling to the leads. The simplest model, which describes properly these peculiarities, is a single electron with energy ϵ_0 interacting with a single vibron with frequency ω_0 (Fig. 1), and coupled to two noninteracting equilibrium electrodes.

We analyze here the electron-vibron model developing the preliminary results obtained in our previous publications [14, 15]. We consider a molecule coupled to free conduction electrons in the leads by a usual tunneling Hamiltonian. Furthermore, the electrons are coupled to vibrational modes. The full Hamiltonian is the sum of the molecular Hamiltonian $\hat{H}_M$, the Hamiltonians of the leads $\hat{H}_{R(L)}$, the tunneling Hamiltonian $\hat{H}_T$ describing the molecule-to-lead coupling, the vibron Hamiltonian $\hat{H}_V$ including electron-vibron interaction and coupling of vibrations to the environment (describing dissipation of vibrons)

$$\hat{H} = \hat{H}_M + \hat{H}_V + \hat{H}_L + \hat{H}_R + \hat{H}_T. \qquad (1)$$

A molecule is described by a set of localized states $|\alpha\rangle$ with energies ϵ_α and inter-orbital overlap integrals $t_{\alpha\beta}$ by the following model Hamiltonian:

$$\hat{H}_M^{(0)} = \sum_\alpha \left(\epsilon_\alpha + e\varphi_\alpha(t)\right) d_\alpha^\dagger d_\alpha + \sum_{\alpha\neq\beta} t_{\alpha\beta} d_\alpha^\dagger d_\beta, \qquad (2)$$

where $d_\alpha^\dagger$,d_α are creation and annihilation operators in the states $|\alpha\rangle$, and $\varphi_\alpha(t)$ is the (self-consistent) electrical potential. The index α is used to mark single-electron states (atomic orbitals) including the spin degree of freedom. The parameters of a tight-binding model could be determined by *ab initio* methods [3]. This is a compro-

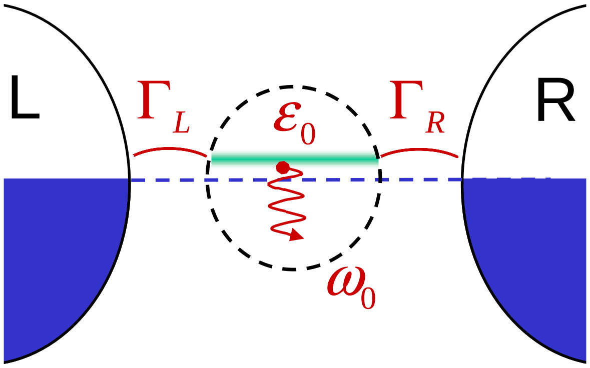

Figure 1: (Color online) Schematic picture of the considered fluctuating single-level model.

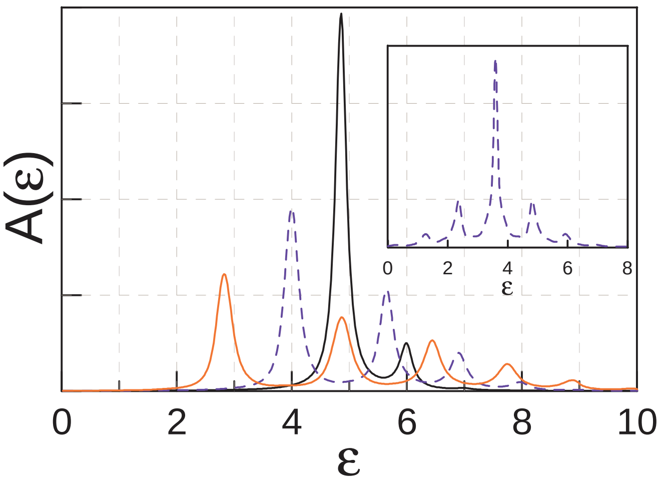

Figure 2: (Color online) Spectral function at different electron-vibron couplings: $\lambda/\omega_0 = 0.4$ (black), $\lambda/\omega_0 = 1.2$ (blue, dashed), and $\lambda/\omega_0 = 2$ (red); at $\epsilon_0/\omega_0 = 5$, $\Gamma_L/\omega_0 = \Gamma_R/\omega_0 = 0.1$. In the insert the spectral function at $\lambda/\omega_0 = 1.2$ is shown at finite voltage, when the level is partially filled. Energies are in units of $\hbar\omega_0$.

mise, which allows us to consider complex molecules with a relatively simple model.

The isolated single-level electron-vibron model is described by the Hamiltonian ($\hbar = 1$)

$$\hat{H}_{M+V} = (\epsilon_0 + e\varphi_0) d^\dagger d + \omega_0 a^\dagger a + \lambda \left(a^\dagger + a\right) d^\dagger d, \quad (3)$$

where the first and the second terms describe the free electron state and the free vibron, and the third term is electron-vibron minimal coupling interaction.

The electrical potential of the molecule φ_0 plays an important role in transport at finite voltages. It describes the shift of the molecular level by the bias voltage, which is divided between the left lead (tip), the right lead (substrate), and the molecule as $\varphi_0 = \varphi_R + \eta(\varphi_L - \varphi_R)$ [16].

The Hamiltonians of the right (R) and left (L) leads read

$$\hat{H}_{i=L(R)} = \sum_{k\sigma} (\epsilon_{ik\sigma} + e\varphi_i) c^\dagger_{ik\sigma} c_{ik\sigma}, \quad (4)$$

$\varphi_i(t)$ are the electrical potentials of the leads. Finally, the tunneling Hamiltonian

$$\hat{H}_T = \sum_{i=L,R} \sum_{k\sigma,\alpha} \left(V_{ik\sigma,\alpha} c^\dagger_{ik\sigma} d_\alpha + \text{h.c.} \right) \quad (5)$$

describes the hopping between the leads and the molecule. A direct hopping between two leads is neglected.

Though the model described above has a long history, the many questions are not answered up to now. While the isolated electron-vibron model can be solved exactly by the so-called polaron or Lang-Firsov transformation, the coupling to the leads produces a true many-body problem. The inelastic resonant tunneling of electrons coupled to phonons was first considered in Refs. [17, 18, 19, 20]. There the exact solution in the single-particle approximation was derived, ignoring completely the Fermi sea in the leads. At strong electron-vibron couplings and weak couplings to the leads the satellites of the main resonant peak are formed in the spectral function (Fig. 2). The question which remains is whether these side-bands can be observed in the differential conductance. New theoretical treatments were presented in Refs. [21, 22, 23, 24, 25, 26, 27, 28, 29, 30, 31, 32]. In parallel, the theory of inelastic resonant tunneling in scanning tunneling spectroscopy was developed [33, 34, 35].

The essential progress in calculation of transport properties in the strong electron-vibron interaction limit has been made with the help of the master equation approach [23, 26, 31]. This method, however, is valid only in the limit of very weak molecule-to-lead couplings and neglects all spectral effects, which are the most important at finite coupling to the leads.

Our approach is based on the nonequilibrium Green function technique [36, 37, 38], which is now a standard method in mesoscopic physics and molecular electronics. We follow the formulation pioneered by Meir, Wingreen, and Jauho [39, 40, 41]. This method was also further developed in Refs. [24, 27, 28, 29, 32, 35]. The case of intermediate and strong electron-vibron couplings *at finite tunneling rates* is the most interesting, but also the most difficult. Only the approaches by Flensberg [24], and Galperin, Ratner, and Nitzan [32] exist, both starting from the exact solution for the isolated system and then switching on tunneling as a perturbation. Our approach is exact for non-interacting systems with arbitrary tunneling coupling, and is approximate in the strong electron-vibron coupling limit without tunneling. Still, its advantage is clear in the truly *nonequilibrium* formulation.

The current in the left ($i = L$) or right ($i = R$) contact to the molecule is described by the well-known expression

$$\begin{aligned} J_{i=L,R} = \frac{\mathrm{i}e}{\hbar} \int \frac{d\epsilon}{2\pi} \mathrm{Tr} \left\{ \mathbf{\Gamma}_i(\epsilon - e\varphi_i) \left(\mathbf{G}^<(\epsilon) + \right.\right. \\ \left.\left. f_i^0(\epsilon - e\varphi_i) \left[\mathbf{G}^R(\epsilon) - \mathbf{G}^A(\epsilon) \right] \right) \right\}, \end{aligned} \quad (6)$$

where $f_i^0(\epsilon)$ is the equilibrium Fermi distribution function in the lead i with the chemical potential μ_i, and the level-width function $\mathbf{\Gamma}_{i=L(R)}(\epsilon) \equiv \Gamma_{i\alpha\beta}(\epsilon)$ is

$$\Gamma_{i\alpha\beta}(\epsilon) = 2\pi \sum_{k\sigma} V_{ik\sigma,\beta} V^*_{ik\sigma,\alpha} \delta(\epsilon - \epsilon_{ik\sigma}). \quad (7)$$

The lesser (retarded, advanced) Green function matrix of a nonequilibrium molecule $\mathbf{G}^{<(R,A)} \equiv G^{<(R,A)}_{\alpha\beta}$ can be found from the Dyson-Keldysh equations in the integral form

$$\mathbf{G}^R(\epsilon) = \mathbf{G}^R_0(\epsilon) + \mathbf{G}^R_0(\epsilon) \mathbf{\Sigma}^R(\epsilon) \mathbf{G}^R(\epsilon), \quad (8)$$

$$\mathbf{G}^<(\epsilon) = \mathbf{G}^R(\epsilon) \mathbf{\Sigma}^<(\epsilon) \mathbf{G}^A(\epsilon), \quad (9)$$

or from the corresponding equations in the differential form (see Refs. 14, 15 and references therein).

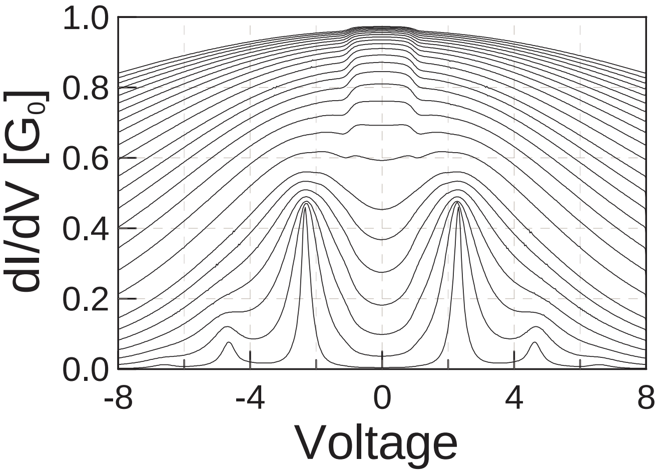

Figure 3: Differential conductance of a *symmetric* junction ($\eta = 0.5$, $\Gamma_R = \Gamma_L$) at different molecule-to-lead coupling, from $\Gamma_L/\omega_0 = 0.1$ (lower curve) to $\Gamma_L/\omega_0 = 10$ (upper curve), $\lambda/\omega_0 = 1$, $\epsilon_0/\omega_0 = 2$. Voltage is in the units of $\hbar\omega_0$.

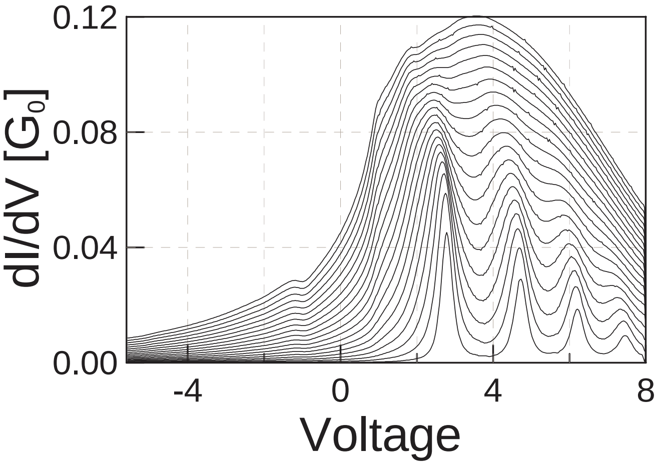

Figure 4: Differential conductance of an *asymmetric* junction ($\eta = 0$, $\Gamma_R = 20\Gamma_L$) at different molecule-to-lead coupling, from $\Gamma_R/\omega_0 = 0.2$ (lower curve) to $\Gamma_R/\omega_0 = 4$ (upper curve), $\lambda/\omega_0 = 2$, $\epsilon_0/\omega_0 = 5$. The voltage is in the units of $\hbar\omega_0$

Here $\mathbf{\Sigma}^{R,<} = \mathbf{\Sigma}_L^{R,<(T)} + \mathbf{\Sigma}_R^{R,<(T)} + \mathbf{\Sigma}^{R,<(V)}$ is the total self-energy of the molecule composed of the tunneling (coupling to the left and right leads) self-energies $\mathbf{\Sigma}_{j=L,R}^{R,<(T)} \equiv \Sigma_{j\alpha\beta}^{R,<(T)} = \sum_{k\sigma}\left\{V_{jk\sigma,\alpha}^{*}G_{jk\sigma}^{R,<}V_{jk\sigma,\beta}\right\}$, and the vibronic self-energy $\mathbf{\Sigma}^{R,<(V)} \equiv \Sigma_{\alpha\beta}^{R,<(V)}$. Here we assume, that vibrons are in equilibrium and are not excited by the current, so that the self-consistent Born approximation is a good starting point. The corresponding self-energies can be found in Refs. [14, 15, 26, 27, 28, 29, 35, 38, 41].

For the single-level model all equations are significantly simplified. Combining J_L and J_R the expression for the current can be written for energy independent $\Gamma_{L(R)}$ (wide-band limit) as

$$J = \frac{e}{2\pi\hbar}\frac{\Gamma_L\Gamma_R}{\Gamma_R+\Gamma_L}\int d\epsilon A(\epsilon)\left[f^0(\epsilon - e\varphi_L) - f^0(\epsilon - e\varphi_R)\right]. \tag{10}$$

It looks as simple as the Landauer-Büttiker formula, but it is not trivial, because the spectral density $A(\epsilon) = -2\mathrm{Im}G^R(\epsilon)$ now depends on the distribution function of electrons inside the fluctuating molecule and hence the applied voltage, $\varphi_L = -\varphi_R = V/2$ [14]. A typical example of the spectral function at zero voltage is shown in Fig. 2. At finite voltage it is calculated self-consistently.

Before considering the experiments, let us discuss a general picture of the vibronic transport in symmetric and asymmetric molecular bridges coupled to the electrodes, provided in experiments by the MCBJ and STM technique, respectively. The differential conductance, calculated at different molecule-to-lead coupling, is shown in Fig. 3 (symmetric) and Fig. 4 (asymmetric). At weak coupling, the vibronic side-band peaks are observed, reproducing the corresponding peaks in the spectral function (Fig. 2). At strong couplings the broadening of the electronic state hides the side-bands, and new features become visible. In the symmetric junction, a suppression of the conductance at $V \simeq \pm\hbar\omega_0$ takes place as a result of inelastic scattering of the coherently transformed from the left lead to the right lead electrons. In the asymmetric junction, the usual IETS increasing of the conductance is observed at a negative voltage $V \simeq -\hbar\omega_0$, this feature is weak and can be observed only in the incoherent tail of the resonant conductance. We conclude, that the vibronic contribution to the conductance can be distinguished clearly in both coherent and tunneling limits.

Now let us discuss the STS experiments [10, 11, 12, 13]. Here we concentrate mainly on the dependence on the tip-to-molecule distance [11]. When the tip (left lead in our notations) is far from the molecule, the junction is strongly asymmetric: $\Gamma_L \ll \Gamma_R$ and $\eta \to 0$, and the conductance is similar to that shown in Fig. 4. When the tip is close to the molecule, the junction is approximately symmetric: $\Gamma_L \approx \Gamma_R$ and $\eta \approx 0.5$, and the conductance curve is of the type shown in Fig. 3. We calculated the transformation of the conductance from the asymmetric to symmetric case (Fig. 5). It is one new feature appeared in asymmetric case due to the fact that we started from a finite parameter $\eta = 0.2$ (in the Fig. 4 $\eta = 0$), namely a single peak at negative voltages, which is shifted to smaller voltage in the symmetric junction. The form and behavior of this peak is in agreement with experimental results [11].

In conclusion, at weak molecule-to-lead (tip, substrate) coupling the usual vibronic side-band peaks in the differential conductance are observed; at stronger coupling to the leads (broadening) these peaks are transformed into step-like features. A vibronic-induced decreasing of the conductance with voltage is observed in high-conductance junctions. The usual IETS feature (increasing of the conductance) can be observed only in the case of low off-resonant conductance. By changing independently the bias voltage and the tip position, it is possible

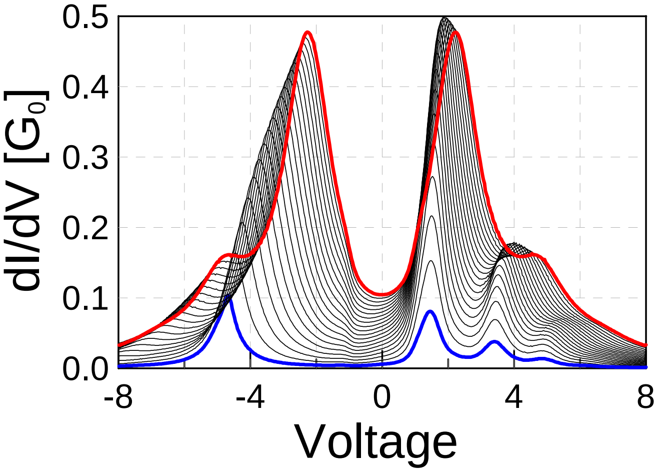

Figure 5: (Color online) Differential conductance at different molecule-to-STM coupling (see the text), from *asymmetric* junction with $\Gamma_L/\omega_0 = 0.025$, $\Gamma_R/\omega_0 = 0.5$ and $\eta = 0.2$ (lower curve, blue thick line) to *symmetric* junction with $\Gamma_L/\omega_0 = \Gamma_R/\omega_0 = 0.5$ and $\eta = 0.5$ (upper curve, red thick line), $\lambda/\omega_0 = 1$, $\epsilon_0/\omega_0 = 2$. Voltage is in the units of $\hbar\omega_0$

to determine the energy of molecular orbitals and the spectrum of molecular vibrations. In the multi-level systems with strong electron-electron interaction further effects, such as Coulomb blockade and Kondo effect, could dominate over the physics which we address here; these effects have to be included in a subsequent step.

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